NSN 5961-01-241-0630

Photo Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-241-0630 **Inclosure Material:** Metal **Overall Length:** 0.350 inches **Terminal Length:** 0.100 inches **Overall Height:** 0.215 inches **Overall Width:** 0.325 inches **Internal Configuration:** Junction contact **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 80.0 collector to emitter voltage/static/base open **Current Rating Per Characteristic:** 80.00 milliamperes source cutoff current preset **Power Rating Per Characteristic:** 250.0 milliwatts small-signal input power, common-collector preset **Special Features:** Junction pattern arrangement: pn **Terminal Type And Quantity:** 14 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli

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